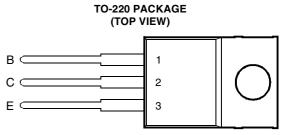
BDW94, BDW94A, BDW94B, BDW94C PNP SILICON POWER DARLINGTONS

BOURNS®

- Designed for Complementary Use with BDW93, BDW93A, BDW93B and BDW93C
- 80 W at 25°C Case Temperature
- 12 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 5 A



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	BDW94		-45	
Collector-base voltage (I _E = 0)	BDW94A	V	-60	v
	BDW94B	V _{CBO}	-80	v
	BDW94C		-100	
	BDW94		-45	
Callector emitter veltere (I 0)	BDW94A	V	-60	V
Collector-emitter voltage ($I_B = 0$)	BDW94B	V _{CEO}	-80	
	BDW94C		-100	
Emitter-base voltage			-5	V
Continuous collector current			-12	A
Continuous base current			-0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P _{tot}	80	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P _{tot}	2	W
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Operating free-air temperature range			-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.64 W/°C.

2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

BDW94, BDW94A, BDW94B, BDW94C PNP SILICON POWER DARLINGTONS



electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER TEST CONDITIONS			MIN	ТҮР	MAX	UNIT			
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = -100 mA	I _B = 0	(see Note 3)	BDW94 BDW94A BDW94B BDW94C	-45 -60 -80 -100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CB} = -40 V$ $V_{CB} = -60 V$ $V_{CB} = -80 V$ $V_{CB} = -80 V$	-		BDW94 BDW94A BDW94B BDW94C			-1 -1 -1 -1	mA
I _{CBO}	Collector cut-off current	$V_{CB} = -45 V$ $V_{CB} = -60 V$ $V_{CB} = -80 V$ $V_{CB} = -100 V$ $V_{CB} = -45 V$ $V_{CB} = -60 V$ $V_{CB} = -80 V$ $V_{CB} = -100 V$	$I_{E} = 0$	$T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$ $T_{C} = 150^{\circ}C$	BDW94 BDW94A BDW94B BDW94C BDW94 BDW94A BDW94B BDW94C			-0.1 -0.1 -0.1 -5 -5 -5 -5 -5	mA
I _{EBO}	Emitter cut-off current	V _{EB} = -5 V	$I_{\rm C} = 0$					-2	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = -3 V$ $V_{CE} = -3 V$ $V_{CE} = -3 V$	I _C = -10 A I _C = -5 A	(see Notes 3 and	4)	1000 100 750		20000	
V _{CE(sat)}	Collector-emitter saturation voltage	I _B = -20 mA I _B = -100 mA	•	(see Notes 3 and	4)			-2 -3	V
V _{BE(sat)}	Base-emitter saturation voltage	I _B = -20 mA I _B = -100 mA	I _C = -10 A	(see Notes 3 and	4)			-2.5 -4	V
V _{EC}	Parallel diode forward voltage	I _E = -5 A I _E = -10 A	l _B = 0 l _B = 0					-2 -4	V

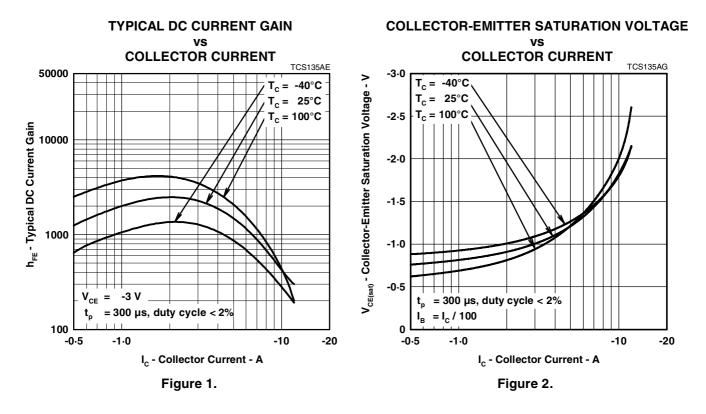
NOTES: 3. These parameters must be measured using pulse techniques, $t_p = 300 \ \mu s$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER		MIN	ТҮР	MAX	UNIT
R _{θJC}	Junction to case thermal resistance			1.56	°C/W
R _{0JA}	Junction to free air thermal resistance			62.5	°C/W

TYPICAL CHARACTERISTICS



BASE-EMITTER SATURATION VOLTAGE vs **COLLECTOR CURRENT** TCS135AI -3.0 = -40°C V_{BE(sat)} - Base-Emitter Saturation Voltage - V тс 25°C Tc = T_c 100°C = -2.5 -2.0 -1.5 -1.0 = I_c / 100 I_B = 300 µs, duty cycle < 2% t, 111 -0.5 -0.5 -1.0 -10 -20 I_c - Collector Current - A Figure 3.

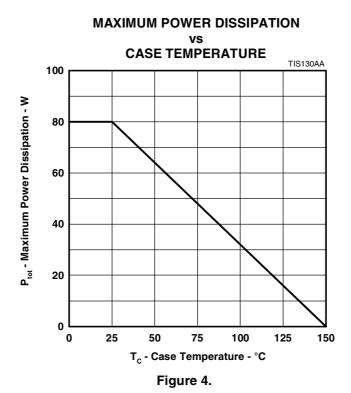
PRODUCT INFORMATION

SEPTEMBER 1993 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.

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THERMAL INFORMATION



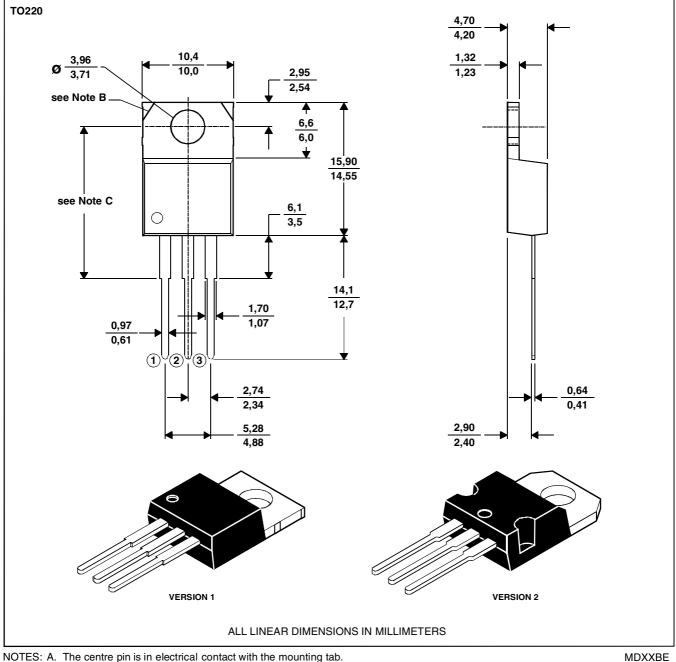
PRODUCT INFORMATION

MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

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